

Source: [Legal](#) > [Area of Law - By Topic](#) > [Patent Law](#) > [Patents](#) > [U.S. Patents](#) > [Reissue Patents](#) (i)

Terms: **38049** ([Edit Search](#))

☒ Select for FOCUS™ or Delivery



759058 (08) RE 38049 March 25, 2003

UNITED STATES PATENT AND TRADEMARK OFFICE GRANTED PATENT
RE **38049**

♦ [Get Drawing Sheet 1 of 5](#)

[Access PDF of Official Patent.](#) (Note: Cost incurred in a later step)

The Adobe Acrobat Reader must be installed on your computer to access Official Patent text.
If you do not have this FREE reader, you can download it now from www.adobe.com.

[Link to Claims Section](#)

March 25, 2003

Optimized container stacked capacitor dram cell utilizing sacrificial oxide deposition and
chemical mechanical polishing

INVENTOR: Dennison, Charles H. - Meridian, Idaho; Walker, Michael A. - Boise, Idaho

APPL-NO: 759058 (08)

FILED-DATE: October 7, 1996

GRANTED-DATE: March 25, 2003

ASSIGNEE-AT-ISSUE: Micron Technology, Inc., Boise, Idaho, 02

LEGAL-REP: Traskbritt

PUB-TYPE: March 25, 2003 - Reissue Patent (E1)

PUB-COUNTRY: United States (US)

REL-DATA:

Continuation of Ser. No. 07/850746, March 13, 1992, GRANTED PATENT 5162248, Utility
Patent having no previously published pre-grant publication (A)

Reissue of: 07/973092, November 6, 1992, PENDING 05270241, December 14, 1993

US-MAIN-CL: 438#396

US-ADDL-CL: 438#253, 438#238, 438#692, 438#633, 216#6

CL: 438, 216

SEARCH-FLD: 148#DIG014, 438#396, 438#397, 438#398, 438#253, 438#254, 438#255,
438#238, 438#692, 438#633, 216#633, 216#6

IPC-MAIN-CL: 7H 01L021#20

PRIM-EXMR: Nguyen, Tuan H.

LexisNexis™ The Total Research System [Practice Area Pages](#) [Change Client](#) [Options](#) [Feedback](#) [Sign Off](#) [Ho](#)

Search [Search Advisor](#) [Get a Document](#) [Shepard's® - Check a Citation](#) [ECLIPSE™](#) [History](#) [Help](#)

Sources [Guided Search Forms](#) [Command Searching](#)

[Legal](#) > [Area of Law - By Topic](#) > [Patent Law](#) > [Patents](#) > [U.S. Patents](#) > [Reissue Patents](#) ⓘ

Enter Search Terms

☒ **Terms and Connectors** ☐ **Natural Language**

38049

Use connectors to show relation of terms (cat or feline, jane w/3 doe) [more...](#)

☒ **Suggest Words and Concepts for Entered Terms**

☒ **Restrict Search Using Document Segments**

Optional: Restrict by Date

☒ **No Date Restrictions** ☐ From To

Search | [Search Advisor](#) | [Get a Document](#) | [Shepard's® - Check a Citation](#)
[Eclipse™](#) | [History](#) | [Delivery Manager](#) | [Practice Area Pages](#) | [Change Client](#) | [Options](#) | [Feedback](#) | [Signoff](#) | [Help](#)
[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

Source: Legal > Area of Law - By Topic > Patent Law > Patents > U.S. Patents > Utility Patents ⓘ
Terms: patno=5162248 (Edit Search)

850746 (07) 5162248 November 10, 1992

UNITED STATES PATENT AND TRADEMARK OFFICE GRANTED PATENT
5162248

♦ GET 1st DRAWING SHEET OF 4
Access PDF of Official Patent. (Note: Cost incurred in a later step)

The Adobe Acrobat Reader must be installed on your computer to access Official Patent text.
If you do not have this FREE reader, you can download it now from www.adobe.com.

[Link to Claims Section](#)

November 10, 1992

Optimized container stacked capacitor DRAM cell utilizing sacrificial oxide deposition and
chemical mechanical polishing

REISSUE: Reissue Application filed Oct. 7, 1996 (O.G. Feb. 4, 1997) Ex. Gp. 1104; Re. S.N.
08/759,058, (O.G. February 4, 1997)

INVENTOR: Dennison, Charles H., Boise, ID; Walker, Michael A., Boise, ID

APPL-NO: 850746 (07)

FILED-DATE: March 13, 1992

GRANTED-DATE: November 10, 1992

ASSIGNEE-AT-ISSUE: Micron Technology, Inc., Boise, ID

ASSIGNEE-AFTER-ISSUE: March 13, 1992 - ASSIGNMENT OF ASSIGNORS INTEREST.,
MICRON TECHNOLOGY, INC. A CORP. OF DELAWA RE 2805 E. COLUMBIA ROAD BOISE IDAHO
83706, Reel and Frame Number: 006079/0156

LEGAL-REP: Paul, David J.

PUB-TYPE: November 10, 1992 - Utility Patent having no previously published pre-grant
publication (A)

PUB-COUNTRY: United States (US)

US-MAIN-CL: 438#396

CL: 438

SEARCH-FLD: 437#47, 437#48, 437#52, 437#60, 437#228, 437#235, 437#919,
437#985, 357#236, 365#149

IPC-MAIN-CL: H 01L021#70

PRIM-EXMR: Thomas, Tom

REF-CITED:

LexisNexis™ The Total Research System [Practice Area Pages](#) [Change Client](#) [Options](#) [Feedback](#) [Sign Off](#) [Help](#)

Search [Search Advisor](#) [Get a Document](#) [Shepard's® - Check a Citation](#) [ECLIPSE™](#) [History](#) [Help](#)

Sources [Guided Search Forms](#) [Command Searching](#)

[Legal](#) > [Area of Law - By Topic](#) > [Patent Law](#) > [Patents](#) > [U.S. Patents](#) > [Utility Patents](#) ⓘ

Enter Search Terms

☒ **Terms and Connectors** ☐ Natural Language

patno=5162248

Search

Use connectors to show relation of terms (cat or feline; jane w/3 doe) more...

☒ **Suggest Words and Concepts for Entered Terms**

☒ **Restrict Search Using Document Segments**

Optional: Restrict by Date

☒ **No Date Restrictions**

☐

From

To

Search | [Search Advisor](#) | [Get a Document](#) | [Shepard's® - Check a Citation](#)
[Eclipse™](#) | [History](#) | [Delivery Manager](#) | [Practice Area Pages](#) | [Change Client](#) | [Options](#) | [Feedback](#) | [Signoff](#) | [Help](#)
[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

Source: [Legal > Area of Law - By Topic > Patent Law > Patents > U.S. Patents > Utility Patents](#) (i)Terms: **patno=5270241** ([Edit Search](#))

973092 (07) 5270241 December 14, 1993UNITED STATES PATENT AND TRADEMARK OFFICE GRANTED PATENT
5270241♦ [GET 1st DRAWING SHEET OF 4](#)[Access PDF of Official Patent.](#) (Note: Cost incurred in a later step)

The Adobe Acrobat Reader must be installed on your computer to access Official Patent text.
If you do not have this FREE reader, you can download it now from www.adobe.com.

[Link to Claims Section](#)

December 14, 1993

Optimized container stacked capacitor DRAM cell utilizing sacrificial oxide deposition and
chemical mechanical polishing

REISSUE: Reissue Application filed Dec. 12, 2001 (O.G. Apr. 9, 2002) Ex. Gp.: 1634; Re.
S.N. 10/020,741, (O.G. April 9, 2002)

March 25, 2003 - This Patent was reissued as Reissue Patent RE 38,049 (O.G. March 25,
2003)

INVENTOR: Dennison, Charles H., Boise, ID; Walker, Michael A., Boise, ID

APPL-NO: 973092 (07)

FILED-DATE: November 6, 1992

GRANTED-DATE: December 14, 1993

ASSIGNEE-AT-ISSUE: Micron Technology, Inc., Boise, ID

LEGAL-REP: Paul, David J.

PUB-TYPE: December 14, 1993 - Utility Patent having no previously published pre-grant
publication (A)

PUB-COUNTRY: United States (US)

REL-DATA:

Addition of Ser. No. 5162248

Addition of Ser. No. 850746, March 13, 1992

US-MAIN-CL: 438#396

US-ADDL-CL: 216#6, 438#633, 438#692

CL: 438, 216, 438

SEARCH-FLD: 437#47, 437#48, 437#52, 437#60, 437#225, 437#228, 437#235,
437#919, 437#986, 257#306

IPC-MAIN-CL: H 01L021#70

LexisNexis™ The Total Research System [Practice Area Pages](#) [Change Client](#) [Options](#) [Feedback](#) [Sign Off](#) [Help](#)

Search [Search Advisor ▶](#) [Get a Document ▶](#) [Shepard's® - Check a Citation ▶](#) [ECLIPSE™](#) [History](#) [Help](#)

Sources [Guided Search Forms](#) [Command Searching](#)

[Legal](#) > [Area of Law - By Topic](#) > [Patent Law](#) > [Patents](#) > [U.S. Patents](#) > [Utility Patents](#) ⓘ

Enter Search Terms

☒ **Terms and Connectors** ☐ **Natural Language**

patno=5270241

Search

Use connectors to show relation of terms (cat or feline, jane w/3 doe) [more...](#)

☒ **Suggest Words and Concepts for Entered Terms**

☒ **Restrict Search Using Document Segments**

Optional: Restrict by Date

☒ **No Date Restrictions**

☐

From

To

Search | [Search Advisor](#) | [Get a Document](#) | [Shepard's® - Check a Citation](#)
[Eclipse™](#) | [History](#) | [Delivery Manager](#) | [Practice Area Pages](#) | [Change Client](#) | [Options](#) | [Feedback](#) | [Signoff](#) | [Help](#)
[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

WELCOME to QUESTEL.ORBIT- Your Guide to INTELLECTUAL PROPERTY

Query/Command : file pluspat

Query/Command : re38049/pn

**** SS 1: Results 1**

Search statement 2

Query/Command : prt fu legalall max

1 / 1 PLUSPAT -,QUESTEL-ORBIT

PN - USRE38049 E1 20030325 [USRE38049]

TI - (E1) Optimized container stacked capacitor dram cell utilizing sacrificial oxide deposition a mechanical polishing

PA - (E1) MICRON TECHNOLOGY INC (US)

PAO - Micron Technology, Inc., Boise ID [US]

IN - (E1) DENNISON CHARLES H (US); WALKER MICHAEL A (US)

AP - US75905896 19961007 [1996US-0759058]

FD - Reissue of: US5270241 - 19931214
Continuation of: US5162248

PR - US75905896 19961007 [1996US-0759058]
US97309292 19921106 [1992US-0973092]
US85074692 19920313 [1992US-08507461]

IC - (E 1) HOIL-021/20

EC - HOIL-021/02B)C2V2

PCL - ORIGINAL, (O) : 438396000; CROSS-REFERENCE (X) : 438253000 438238000 438692 216006000

DT - Corresponding document

CT - US4432799; US4671851; US4785337; US4877750; US4944836; US5045899; US5150276
US5185282; US5313089; US5364809; JP0286270; JP0094554; JP0074752
"Stacked Capacitor DRAM Cell with Vertical Fins", IBM TDB, Jul. 1990, pp. 245-247.*

"Crown-Shaped Stacked-Capacitor Cell for 1.5-V Operation 64-Mb Dram's" by T. Kaga et
Transactions on Electron Devices, vol. 38, No. 2, Feb. 1991, pp. 255-261.*

"A Stacked Capacitor Cell with Ring Structure" by N. Shinmura et al., pp. 833-836. (Exten
22nd International Conference on Solid State Devices 1990).

STG - (E1) Reissue Patent

AB - An existing stacked capacitor fabrication process is modified to construct a three-dimension container capacitor. The present invention develops the container capacitor by etching an opening into a low etch rate oxide. The contact opening is used as a form for deposited polyconformal oxide, such as ozone TEOS, is deposited over the entire structure thereby bridging across the container. The high etch-rate oxide is planarized back to the thin poly and the resulting excess is removed to separate neighboring containers. The two oxides, having different etch rates, are thereby leaving a free-standing poly container cell with 100% (or all) of the higher etch rate and a pre-determined oxide surrounding the container still intact.

UP - 2003-14

Query/Command : file inpadoc

Query/Command : fam us5270241/pn

1 Patent Groups

**** SS 7: Results 6**

Search statement 8

Query/Command : famstate nonstop

1/6 INPADOC - COINPADOC

PN - DE 4307725 C2 20020814 [DE4307725]
TI - VERFAHREN ZUR HERSTELLUNG EINER STAPELKONDENSATOR-DRAM-ZELLE
IN - DENNISON CHARLES H [US]; WALKER MICHAEL A [US]
PA - MICRON TECHNOLOGY INC [US]
AP - DE 4307725/93-A 19930311 [1993DE-4307725]
PR - US 850746/92-A 19920313 [1992US-0850746]
IC - HO 1 L-021 /8242

1 / 1 LEGALI - ©LEGSTAT

PN - DE 4307725 [DE4307725]
AP - DE 4307725/93 19930311 [1993DE-4307725]
DT - DE-P
ACTE - 19930311 DE/AE-A
DOMESTIC APPLICATION (PATENT APPLICATION)
DE 4307725/93 19930311 [1993DE-4307725]

19930916 DE/A1 [+]
LAYING OPEN FOR PUBLIC INSPECTION

19990512 DE/8110 [+]
REQUEST FOR EXAMINATION PARAGRAPH 44

20020814 DE/D2 [+]
GRANT AFTER EXAMINATION

20030213 DE/8364 [+]
NO OPPOSITION DURING TERM OF OPPOSITION
UP - 2003-07

2 / 6 INPADOC - ©INPADOC

PN - DE 4307725 A1 19930916 [DE4307725]
TI - VERFAHREN ZUR HERSTELLUNG EINER STAPELKONDENSATOR-DRAM-ZELLE
IN - DENNISON CHARLES H [US]; WALKER MICHAEL A [US]
PA - MICRON TECHNOLOGY INC [US]
AP - DE 4307725/93-A 19930311 [1993DE-4307725]
PR - US 850746/92-A 19920313 [1992US-0850746]
IC - H01L-027/108; H01L-021/72

1 / 1 LEGALI - ©LEGSTAT

PN - DE 4307725 [DE4307725]
AP - DE 4307725/93 19930311 [1993DE-4307725]
DT - DE-P
ACTE - 19930311 DE/AE-A
DOMESTIC APPLICATION (PATENT APPLICATION)
DE 4307725/93 19930311 [1993DE-4307725]

19930916 DE/A1 [+]
LAYING OPEN FOR PUBLIC INSPECTION

19990512 DE/8110 [+]
REQUEST FOR EXAMINATION PARAGRAPH 44

20020814 DE/D2 [+]
GRANT AFTER EXAMINATION

20030213 DE/8364 [+]
NO OPPOSITION DURING TERM OF OPPOSITION
UP - 2003-07

3 / 6 INPADOC - ©INPADOC

PN - JP 6013570 A2 19940121 [JP06013570]
TI - OPTIMUM-STACK TYPE CAPACITOR DRAM CELL UTILIZING VAPOR DEPOSITI
SACRIFICE OXIDE FILM AND CHEMICAL/ MECHANICAL POLISHING
IN - CHIYAARUZU EICHI DENISON; MAIKERU EI UOOKAA
PA - MICRON TECHNOLOGY INC
AP - JP 78582/93-A 19930315 [1993JP-0078582]
PR - US 850746/92-A 19920313 [1992US-0850746]
IC - H01L-027/108; H01L-027/04

4 / 6 INPADOC - ©INPADOC

PN - JP 2826036 B2 19981118 [JP2826036]
IN - CHAARUZU EICHI DENISON; MAIKERU EI UOOKAA
PA - MICRON TECHNOLOGY INC
AP - JP 78582/93-A 19930315 [1993JP-0078582]
PR - US 850746/92-A 19920313 [1992US-0850746]
IC - H01L-027/108; H01L-021/822; H01L-021/8242; H01L-027/04

5 / 6 INPADOC - ©INPADOC

PN - US 5162248 A 19921110 [US5162248]
TI - OPTIMIZED CONTAINER STACKED CAPACITOR DRAM CELL UTILIZING SACR DEPOSITION AND CHEMICAL MECHANICAL POLISHING
IN - DENNISON CHARLES H [US]; WALKER MICHAEL A [US]
PA - MICRON TECHNOLOGY INC [US]
AP - US 850746/92-A 19920313 [1992US-0850746]
PR - US 850746/92-A 19920313 [1992US-0850746]
IC - H01L-021/70

1 / 1 LEGALI - ©LEGSTAT

PN - US 5162248 [US5162248]
AP - US 850746/92 19920313 [1992US-0850746]
DT - US-P
ACTE - 19920313 US/AE-A
APPLICATION DATA (PATENT)
US 850746/92 19920313 [1992US-0850746]

19920313 US/AS02
ASSIGNMENT OF ASSIGNOR'S INTEREST
MICRON TECHNOLOGY, INC. A CORP. OF DELAWARE 2805 E. COLUMBIA ROA
8 * DENNISON, CHARLES H. : 19920313; WALKER, MICHAEL A. : 19920313

19921110 US/A
PATENT

19970204 US/RF
REISSUE APPLICATION FILED
961007
UP - 1999-13

6 / 6 INPADOC - ©INPADOC

PN - US 5270241 A 19931214 [US5270241]
TI - OPTIMIZED CONTAINER STACKED CAPACITOR DRAM CELL UTILIZING SACR DEPOSITION AND CHEMICAL MECHANICAL POLISHING
IN - DENNISON CHARLES H [US]; WALKER MICHAEL A [US]
PA - MICRON TECHNOLOGY INC [US]
AP - US 973092/92-A 19921106 [1992US-0973092]
PR - US 850746/92-A1 19920313 [1992US-0850746]
IC - H01L-021/70

1 / 1 LEGALI - ©LEGSTAT

PN - US 5270241 [US5270241]
AP - US 973092/92 19921106 [1992US-0973092]
DT - US-P
ACTE - 19921106 US/AE-A
APPLICATION DATA (PATENT)
US 973092/92 19921106 [1992US-0973092]

19931214 US/A
PATENT

20020409 US/RF
REISSUE APPLICATION FILED
20011212
UP - 2002-17

WELCOME TO QUESTEL.ORBIT – Your guide to INTELLECTUAL PROPERTY

Query/Command : file pluspat

Selected file: pluspat

Query/Command : us5270241/pn

**** SS 2: Results 1**

Search statement 3

Query/Command : prt fu legalall max

1 / 1 PLUSPAT - ©QUESTEL-ORBIT - image

PN - US5270241 A 19931214 [US5270241]
TI - (A) Optimized container stacked capacitor DRAM cell utilizing sacrificial oxide deposition mechanical polishing
PA - (A) MICRON TECHNOLOGY INC (US)
PA0 - Micron Technology, Inc., Boise ID [US]
IN - (A) DENNISON CHARLES H (US); WALKER MICHAEL A (US)
AP - US97309292 19921106 [1992US-0973092]
FD - Cont. of US850746 19920313 [1992US-0850746]
 Continuation of: US5162248
PR - US97309292 19921106 [1992US-0973092]
 US85074692 19920313 [1992US-0850746]
IC - (A) H01L-021/70
EC - H01L-021/02B3C2D
 H01L-021/02B3C2V2
PCL - ORIGINAL (O) : 438396000; CROSS-REFERENCE (X) : 216006000 257E21014 257E21
 438692000
DT - Corresponding document
CT - US4671851; US4944836; US5045899; JP0286270; JP0074752; JP0094554
 "Stacked Capacitor DRAM Cell with Vertical Fins" IBM TDB, Jul. 1990, pp. 245-247.
 "Crown-Shaped Stacked-Capacitor Cell for 1.5-V Operation 64-Mb Dram's" by T. Kaga et
 Transactions on Electron Devices, vol. 38, No. 2, Feb. 1991, pp. 255-261.
 "A Stacked Capacitor Cell with Ring Structure" by N. Shinmura et al., pp. 833-836. (Exten
 the 22rd International Conference on Solid State Devices, 1990).
STG - (A) United States patent
AB - An existing stacked capacitor fabrication process is modified to construct a three-dimension
 container capacitor. The present invention develops the container capacitor by etching an o
 opening) into a low etch rate oxide. The contact opening is used as a form for deposited po
 conforms to the sides of the opening walls. Within the thin poly lining of the oxide contain
 oxide, such as ozone TEOS, is deposited over the entire structure thereby bridging across th
 container. The high etch-rate oxide is planarized back to the thin poly and the resulting exp
 removed to separate neighboring containers. The two oxides, having different etch rates, ar
 thereby leaving a free-standing poly container cell with 100% (or all) of the higher etch rate
 and a pre-determined oxide surrounding the container still intact.

1 / 1 LGST - ©LEGSTAT

PN - US 5270241 [US5270241]
AP - US 973092/92 19921106 [1992US-0973092]
DT - US-P
ACT - 19921106 US/AE-A
APPLICATION DATA (PATENT)
US 973092/92 19921106 [1992US-0973092]

19931214 US/A
PATENT

20020409 US/RF
REISSUE APPLICATION FILED
20011212
UP - 2002-17

1 / 1 CRXX - ©CLAIMS/RRX

AN - 2426555
PN - 5,270,241 A 19931214 [US5270241]
PA - Micron Technology Inc
PT - C (Chemical)
ACT - 20011212 REISSUE REQUESTED
ISSUE DATE OF O.G.: 20020409
REISSUE REQUEST NUMBER: 10/020741
EXAMINATION GROUP RESPONSIBLE FOR REISSUEPROCESS: 1634

Reissue Patent Number:

UP - 2002-15
UACT - 2002-04-09

LexisNexis™ The Total Research System [Practice Area Pages](#) [Change Client](#) [Options](#) [Feedback](#) [Sign Off](#) [Home](#)

Search [Search Advisor](#) [Get a Document](#) [Shepard's® - Check a Citation](#) [ECLIPSE™](#) [History](#) [Help](#)

Sources [Guided Search Forms](#) [Command Searching](#)

[Legal](#) > [Area of Law - By Topic](#) > [Patent Law](#) > [Legal News](#) > [Patent, Trademark & Copyright Periodicals, Combined](#) [?](#)

Enter Search Terms

☒ **Terms and Connectors** ☐ **Natural Language**

5270241 or 5,270,241 [Search](#)

Use connectors to show relation of terms (cat or feline, jane w/3 doe) [more...](#)

☒ **Suggest Words and Concepts for Entered Terms**

☒ **Restrict Search Using Document Segments**

Optional: Restrict by Date

☒ **No Date Restrictions** ☐ **From** **To**

[Search](#) | [Search Advisor](#) | [Get a Document](#) | [Shepard's® - Check a Citation](#)
[Eclipse™](#) | [History](#) | [Delivery Manager](#) | [Practice Area Pages](#) | [Change Client](#) | [Options](#) | [Feedback](#) | [Signoff](#) | [Help](#)
[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

No Documents Found!

No documents were found for your search (**5270241** or **5,270,241**). Please edit your search and try again. You may want to try one or more of the following:

- Check for spelling errors.
- Remove some search terms.
- Use more common search terms.
- If applicable, look for all dates.

Edit Search

[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

LexisNexis™ The Total Research System [Practice Area Pages](#) [Change Client](#) [Options](#) [Feedback](#) [Sign Off](#) [Ho](#)

Search [Search Advisor](#) [Get a Document](#) [Shepard's® - Check a Citation](#) [ECLIPSE™](#) [History](#) [Help](#)

Sources [Guided Search Forms](#) [Command Searching](#)

[Legal](#) > [Area of Law - By Topic](#) > [Patent Law](#) > [Multi-Source Groups](#) > [Patent Cases from Federal Courts and Administrative Materials](#) [i](#)

Enter Search Terms

☒ **Terms and Connectors** ☐ **Natural Language**

5270241 or 5,270,241

Search

Use connectors to show relation of terms (cat or feline, jane w/3 doe) [more...](#)

☒ **Suggest Words and Concepts for Entered Terms**

☒ **Restrict Search Using Document Segments**

Optional: Restrict by Date

☒ **No Date Restrictions**

☐

From

To

Search | [Search Advisor](#) | [Get a Document](#) | [Shepard's® - Check a Citation](#)
[Eclipse™](#) | [History](#) | [Delivery Manager](#) | [Practice Area Pages](#) | [Change Client](#) | [Options](#) | [Feedback](#) | [Signoff](#) | [Help](#)
[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

No Documents Found!

No documents were found for your search (**5270241** or **5,270,241**). Please edit your search and try again. You may want to try one or more of the following:

- Check for spelling errors.
- Remove some search terms.
- Use more common search terms.
- If applicable, look for all dates.

Edit Search

[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

LexisNexis™ The Total Research System [Practice Area Pages](#) [Change Client](#) [Options](#) [Feedback](#) [Sign Off](#) [Help](#)

Search [Search Advisor](#) [Get a Document](#) [Shepard's® - Check a Citation](#) [ECLIPSE™](#) [History](#) [Help](#)

Sources [Guided Search Forms](#) [Command Searching](#)

[News & Business](#) > [News](#) > [News Group File, All](#) [i](#)

Enter Search Terms

☒ **Terms and Connectors** ☐ **Natural Language**

5270241 or 5,270,241 [Search](#)

Use connectors to show relation of terms (cat or feline, jane w/3 doe) [more...](#)

☒ **Suggest Words and Concepts for Entered Terms**

☒ **Restrict Search Using Document Segments**

Optional: Restrict by Date

☒ **No Date Restrictions** ☐ From To

Search | [Search Advisor](#) | [Get a Document](#) | [Shepard's® - Check a Citation](#)
[Eclipse™](#) | [History](#) | [Delivery Manager](#) | [Practice Area Pages](#) | [Change Client](#) | [Options](#) | [Feedback](#) | [Signoff](#) | [Help](#)
[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.

No Documents Found!

No documents were found for your search (**5270241** or **5,270,241**). Please edit your search and try again. You may want to try one or more of the following:

- Check for spelling errors.
- Remove some search terms.
- Use more common search terms.
- If applicable, look for all dates.

Edit Search

[About LexisNexis](#) | [Terms and Conditions](#)

Copyright © 2003 LexisNexis, a division of Reed Elsevier Inc. All rights reserved.